



Sensors for Intelligent Systems

A Detailed MEMS Example

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Micralyne Introduction



A top independent MEMS provider

Located in Edmonton, Alberta, Canada

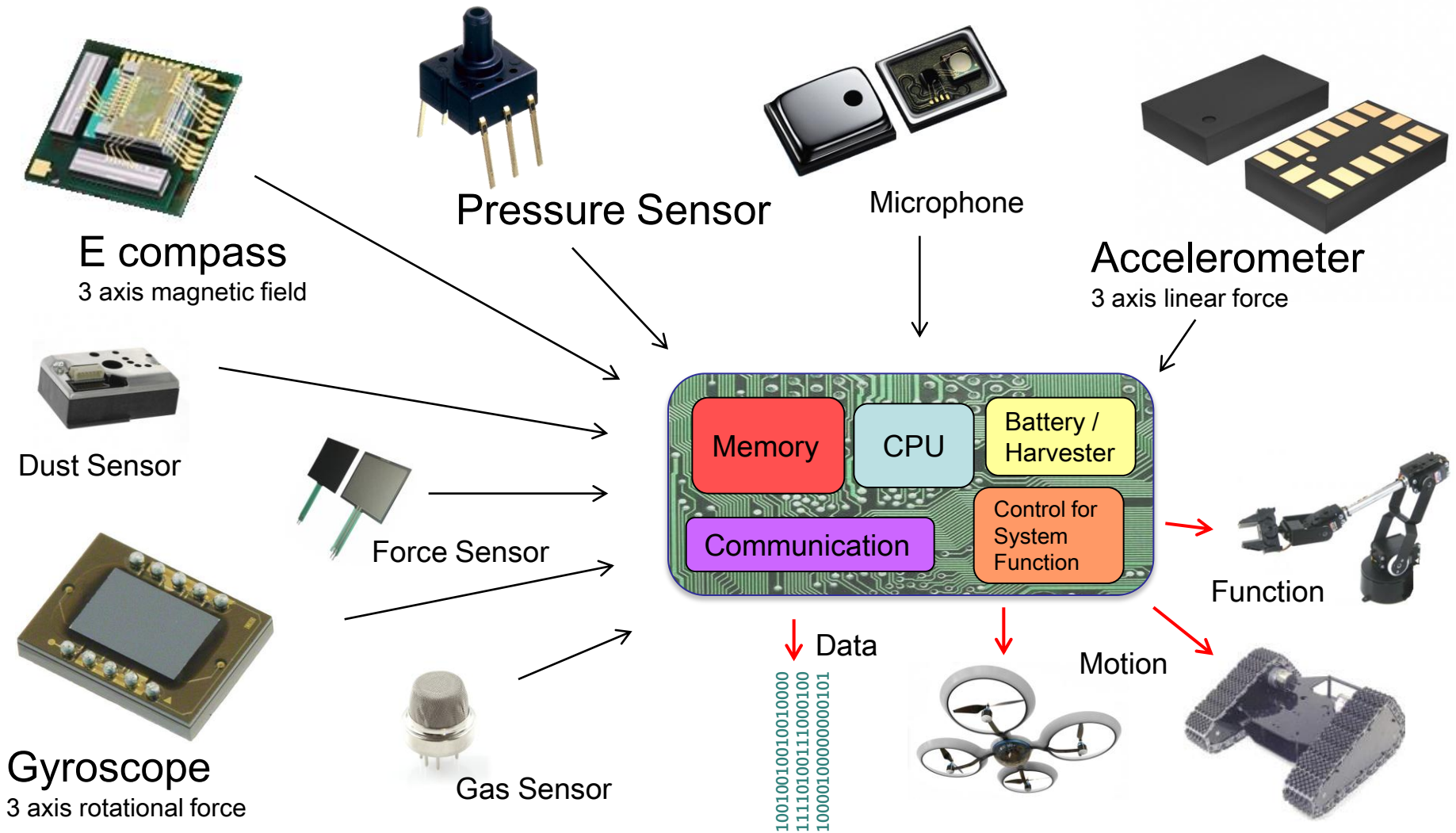
Founded in 1982 and privatized in 1998

55,000 sq ft. (5000 m²) MEMS facility

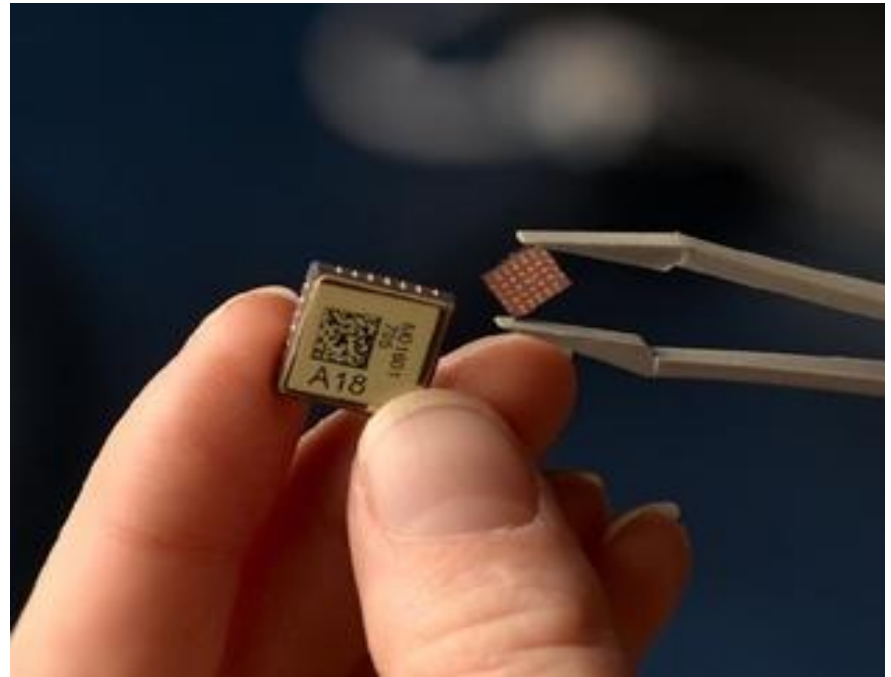
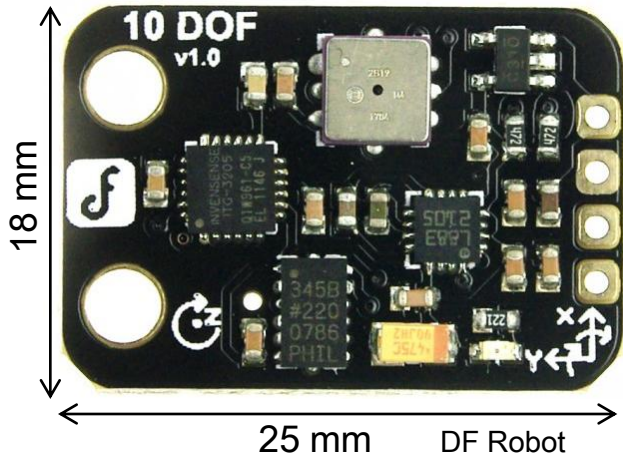
Sensors, Optical, Medical, and other MEMS devices

Development and Manufacturing of Complex MEMS

MEMS and Microfabricated Sensors for Intelligent Systems



Sensor Trends – Miniaturization, Integration, Cost



9-Axis Sensors



▼ Absolute Orientation Sensors

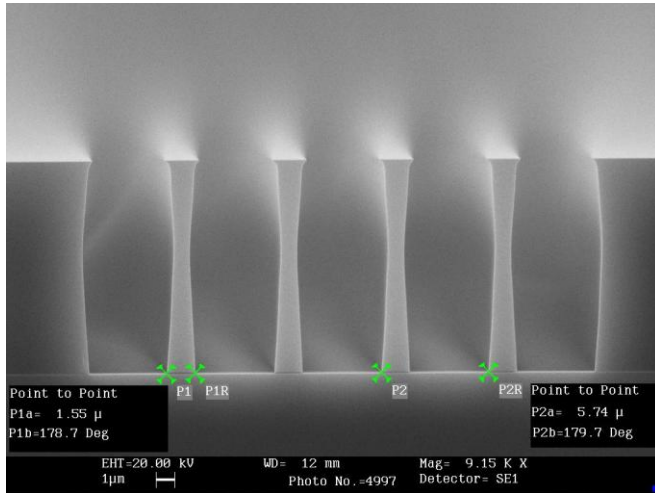
Product	Measurement range	Size (mm ³)	Digital Resolution	Promotion Status
> BMX055	Accelerometer: ±2g, ±4g, ±8g, ±16 g Gyroscope: ±125°/s, ±250°/s, ±500°/s, ±1000°/s, ±2000°/s Magnetometer: ±1200µT (x,y), ±2500µT (z)	3.0 x 4.5 x 0.95	Accelerometer (A): 0.98 mg Gyroscope (G): 0.004 °/s Magnetometer (M): 0.3 µT	Active

Bosch Sensortec

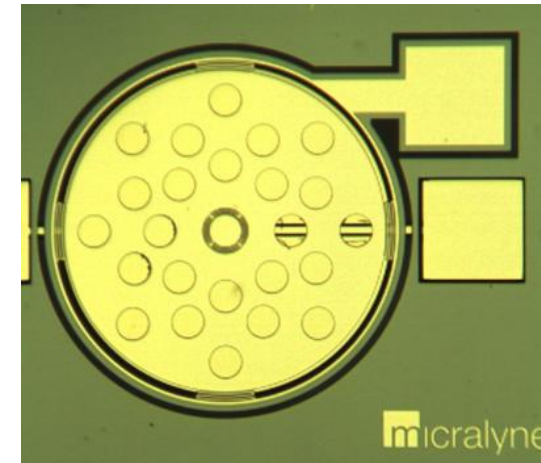
Micralyne Example: High Accuracy Accelerometer

- Eliminate the ceramic package through Wafer Level Packaging.
- MEMS mass and sensing structure is identical.
- Estimated selling price of WLP device is ~1/3 of ceramic packaged version for same functionality.

Microfabrication Process Technology

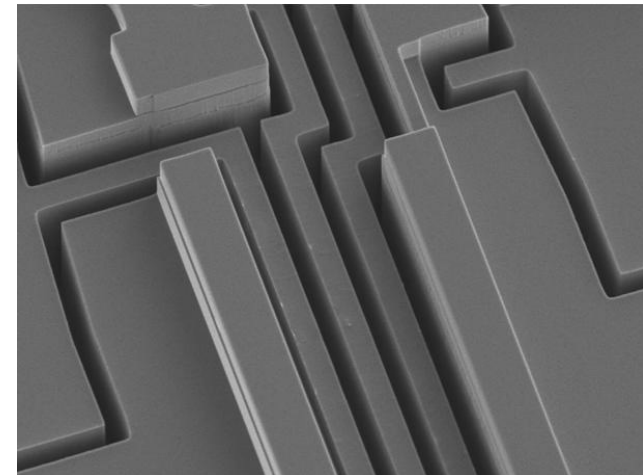
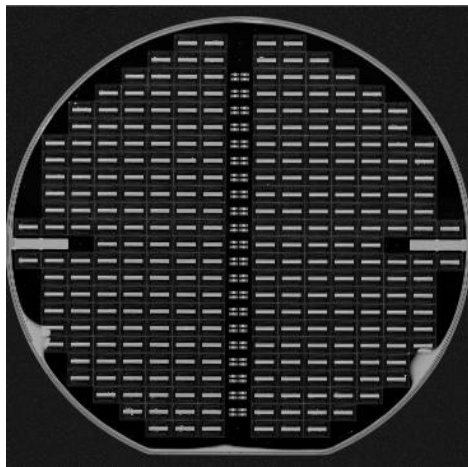


Photolithography (non contact stepper, 0.4 μ m alignment)



Thin Film Deposition (high adhesion, low stress)

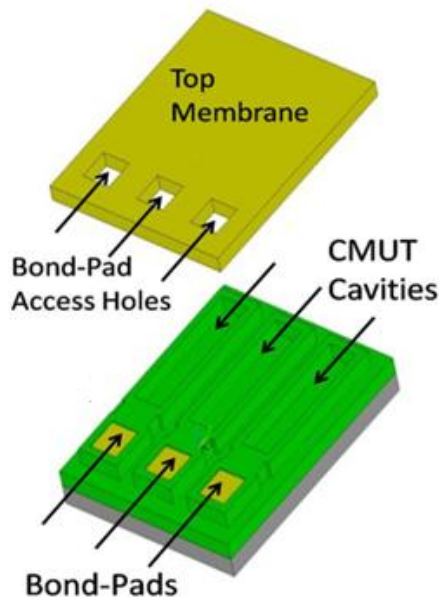
Aligned Wafer
Bonding
Acoustic
Microscope Image



Deep Reactive Ion Etch of silicon (multiple layers)

MEMS Process

Capacitive
Micromachined
Ultrasonic
Transducer



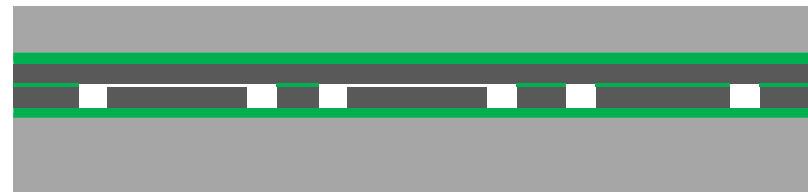
- Highly Doped Si
- Low Doped Si
- Silicon Dioxide
- Gold Thin Film



Trench Etch: 3.5 μm Si (SOI) with top oxide, Trench etch Si, 2 to 4 μm features



Oxide Removal: etch top oxide where CMUT gap is required



Bond: 2nd SOI, silicon to silicon dioxide fusion bond



Remove Top Handle Wafer: remove buried oxide



Top Etch: Isolate top electrodes and open lower electrode bond pads with etch

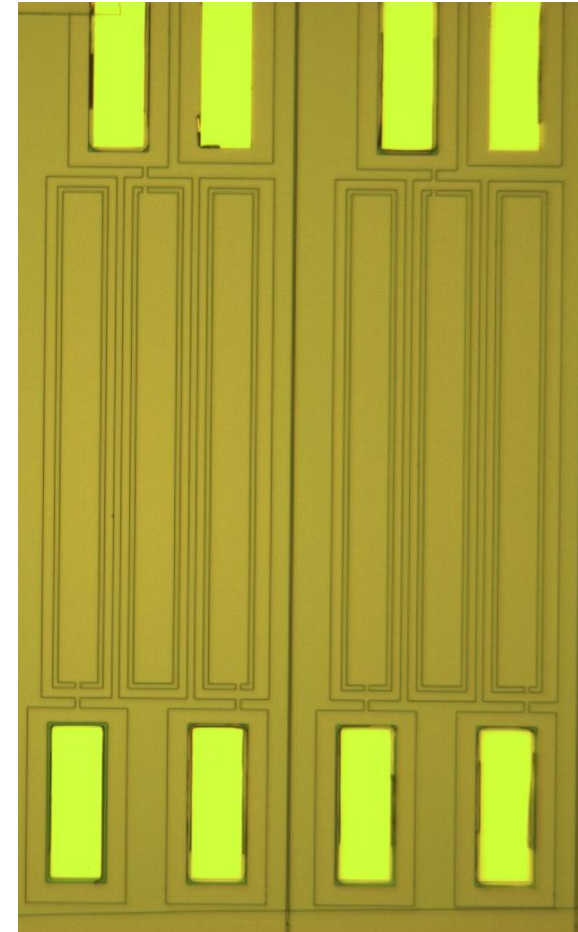
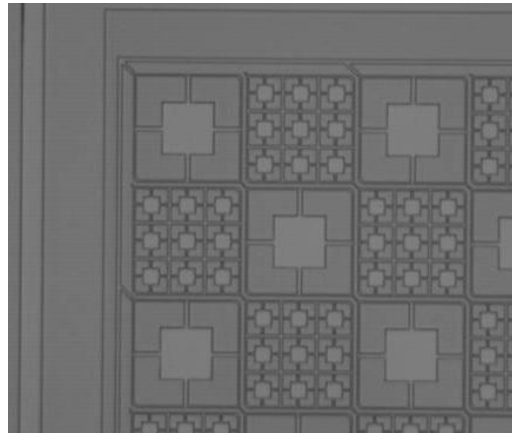
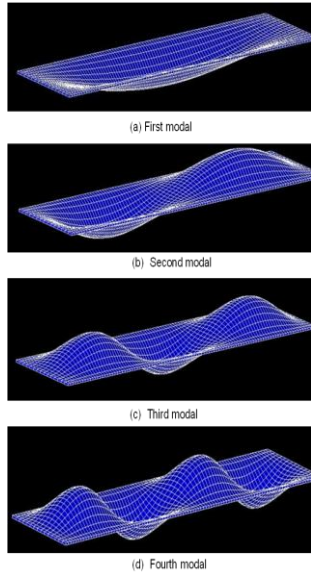


Metal Deposition: deposit contact metal to upper and lower electrodes, dice

CMUT Devices

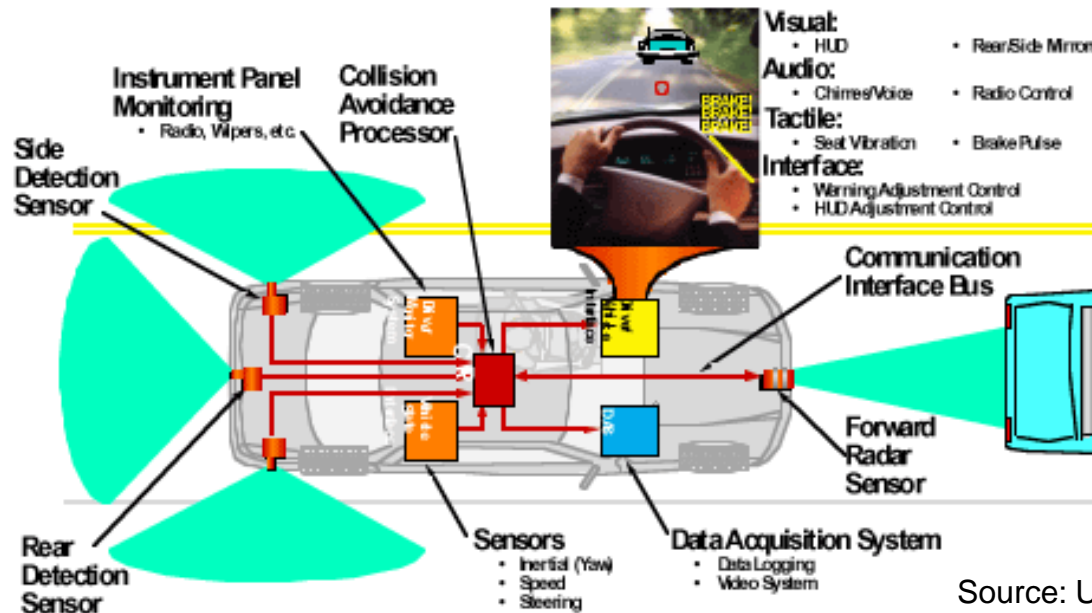
CMUT technology offers many potential advantages over traditional linear array piezoelectric transducer technology, including:

- Advantages of wafer fabrication scale
- 2D arrays offer higher resolution
- Greater sensitivity
- Superior acoustic impedance matching
- Potential to co-integrate with electronics
- Choice of frequencies of interest possible with just a change in geometry



MEMS Sensors for Smart Automobile Systems

- Current warning systems: Back up alarm, blind spot alarm.
- Current and future “Active” systems: park assist, adaptive cruise control, crash avoidance, autonomous vehicles.
- Safety regulation has accelerated the progress of these systems.
 - » MEMS CMUTs will offer multi-frequency arrays as well as superior acoustic coupling.



Google Driverless Car

Source: US Government <http://www.nhtsa.gov>

Summary

- Sensor evolution has enabled Intelligent Systems.
- Successfully driving down size and cost, while increasing integration has led to wide scale adoption.
- MEMS technology has displaced several conventional technologies to meet the needs of Systems and this will continue.
- We are in the start the sensor revolution and It's exciting to see what the future holds for this technology.

Thank you

Questions?

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